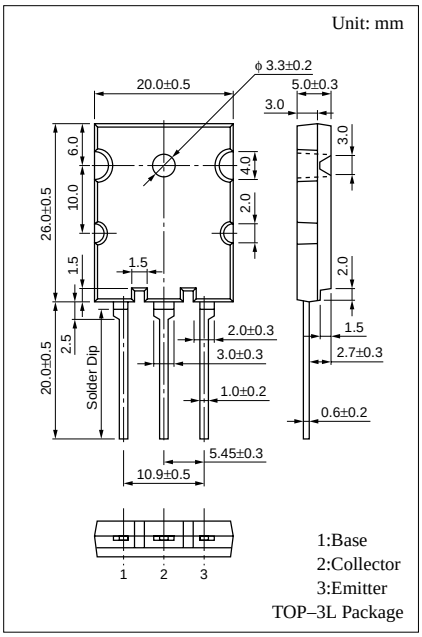
2SB1347

Silicon PNP triple diffusion planar type

For high power amplification
Complementary to 2SD2029



Features

- Satisfactory foward current transfer ratio h_{FE} vs. collector current I_C characteristics
- Wide area of safe operation (ASO)
- High transition frequency f_T
- Optimum for the output stage of a HiFi audio amplifier

Absolute Maximum Ratings (T_C=25˚C)

Parameter		Symbol	Ratings	Unit
Collector to base voltage		V_{CBO}	–160	V
Collector to emitter voltage		V_{CEO}	–160	V
Emitter to base voltage		V_{EBO}	–5	V
Peak collector current		I_{CP}	–20	A
Collector current		I_C	–12	A
Collector power dissipation	T_C=25°C	P_C	120	W
	Ta=25°C		3.5	
Junction temperature		T_j	150	˚C
Storage temperature		T_{stg}	–55 to +150	˚C

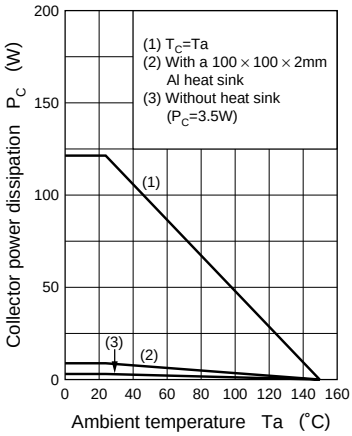
Electrical Characteristics (T_C=25˚C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	I_{CBO}	V_{CB} = –160V, I_E = 0			–50	μA
Emitter cutoff current	I_{EBO}	V_{EB} = –3V, I_C = 0			–50	μA
Forward current transfer ratio	h_{FE1}	V_{CE} = –5V, I_C = –20mA	20			
	h_{FE2}*	V_{CE} = –5V, I_C = –1A	60		200	
	h_{FE3}	V_{CE} = –5V, I_C = –8A	20			
Base to emitter voltage	V_{BE}	V_{CE} = –5V, I_C = –8A			–1.8	V
Collector to emitter saturation voltage	$V_{CE(sat)}$	I_C = –8A, I_B = – 0.8A			–2.0	V
Transition frequency	f_T	V_{CE} = –5V, I_C = – 0.5A, f = 1MHz		15		MHz
Collector output capacitance	C_{ob}	V_{CB} = –10V, I_E = 0, f = 1MHz		400		pF

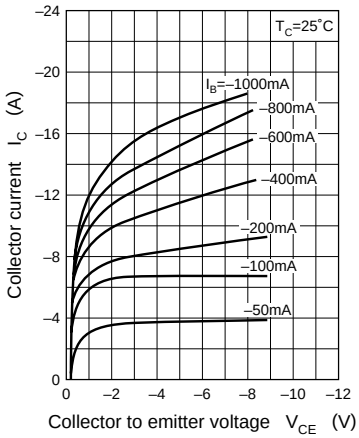
*h_{FE2} Rank classification

Rank	Q	S	P
h_{FE2}	60 to 120	80 to 160	100 to 200

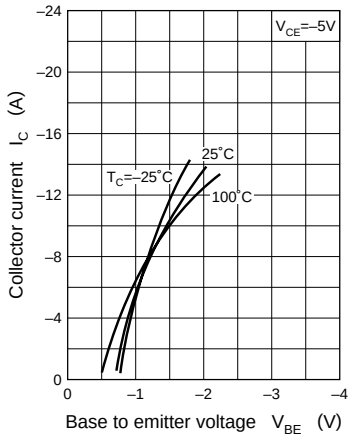
P_C — Ta



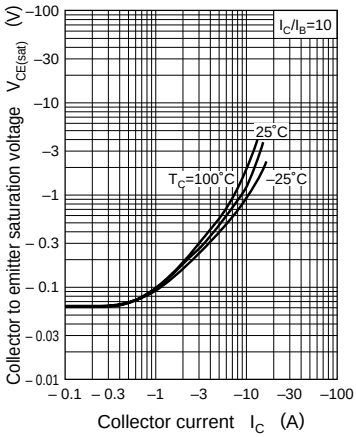
I_C — V_{CE}



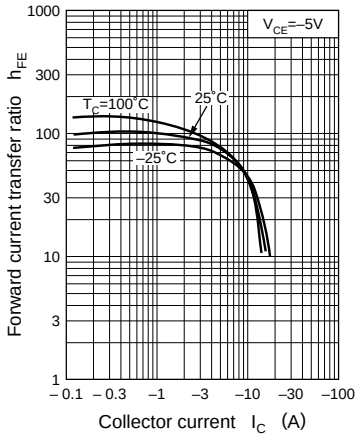
I_C — V_{BE}



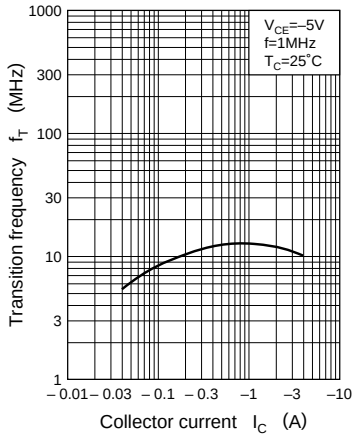
$V_{CE(sat)}$ — I_C



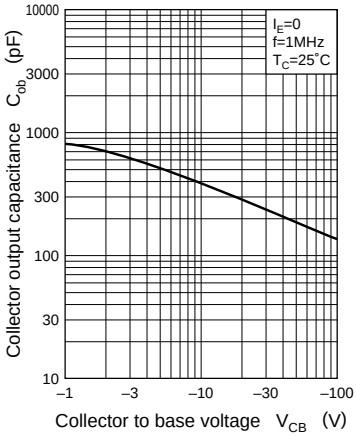
h_{FE} — I_C



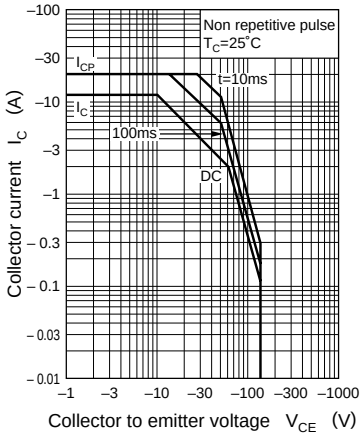
f_T — I_C



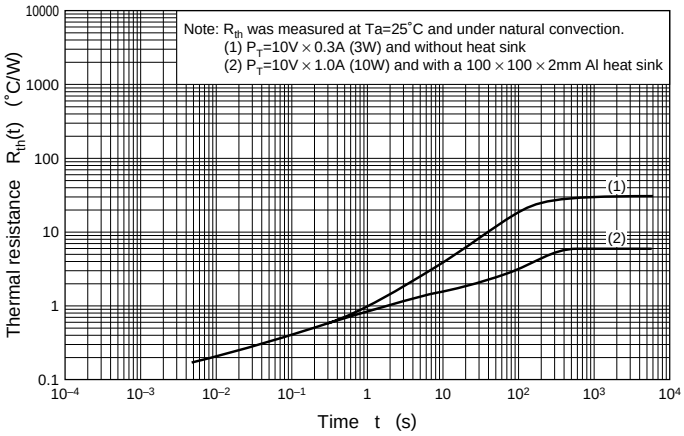
C_{ob} — V_{CB}



Area of safe operation (ASO)



$R_{th(t)}$ — t


Note: R_{th} was measured at Ta=25°C and under natural convection.
(1) P_T=10V × 0.3A (3W) and without heat sink
(2) P_T=10V × 1.0A (10W) and with a 100 × 100 × 2mm Al heat sink
Thermal resistance $R_{th}(t)$ (°C/W)
10000
1000
100
10
1
0.1
10^{-4}
10^{-3}
10^{-2}
10^{-1}
1
10
10^{2}
10^{3}
10^{4}
Time t (s)
(1)
(2)

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